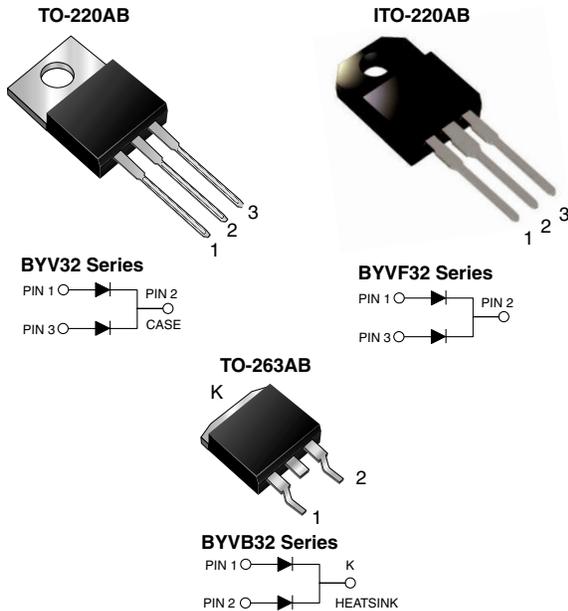


Dual Common-Cathode Ultrafast Rectifier



FEATURES

- Glass passivated chip junction
- Ultrafast recovery time
- Low switching losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- Meets MSL level 1, per J-STD-020C, LF max peak of 245 °C (for TO-263AB package)
- Solder Dip 260 °C, 40 seconds (for TO-220AB & ITO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, free-wheeling diodes, dc-to-dc converters, and other power switching application.

MAJOR RATINGS AND CHARACTERISTICS

$I_{F(AV)}$	18 A
V_{RRM}	50 V to 200 V
I_{FSM}	150 A
t_{rr}	25 ns
V_F	0.85 V
T_j max.	150 °C

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D

E3 suffix for commercial grade, HE3 suffix for high reliability grade (AEC Q101 qualified)

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_C = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	BYV32-50	BYV32-100	BYV32-150	BYV32-200	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	V
Maximum RMS voltage	V_{RMS}	35	70	105	140	V
Maximum DC blocking voltage	V_{DC}	50	100	150	200	V
Maximum average forward rectified current at $T_C = 125\text{ °C}$	$I_{F(AV)}$	18				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	150				A
Operating storage and temperature range	T_J, T_{STG}	- 65 to + 150				°C
Isolation voltage (ITO-220AB only) From terminal to heatsink $t = 1$ minute	V_{AC}	1500				V

ELECTRICAL CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS	SYMBOL	BYV32-50	BYV32-100	BYV32-150	BYV32-200	UNIT
Maximum instantaneous forward voltage per diode ⁽¹⁾	at $I_F = 20\text{ A}$ at $I_F = 5.0\text{ A}$	$T_J = 100\text{ }^\circ\text{C}$ V_F			1.15 0.85		V
Maximum DC reverse current per diode at rated DC blocking voltage		$T_J = 25\text{ }^\circ\text{C}$ $T_J = 100\text{ }^\circ\text{C}$ I_R			10 600		μA
Maximum reverse recovery time per diode	at $I_F = 1\text{ A}$, $V_R = 30\text{ V}$, $di/dt = 100\text{ A}/\mu\text{s}$, $I_{rr} = 10\% I_{RM}$	t_{rr}			25		ns
Typical junction capacitance per diode	at 4.0 V, 1 MHz	C_J			45		pF

Note:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	BYV	BYVF	BYVB	UNIT
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	1.6	5.0	1.6	$^\circ\text{C}/\text{W}$

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	BYV32-200-E3/45	1.85	45	50/Tube	Tube
ITO-220AB	BYVF32-200-E3/45	1.97	45	50/Tube	Tube
TO-263AB	BYVB32-200-E3/45	1.35	45	50/Tube	Tube
TO-263AB	BYVB32-200-E3/81	1.35	81	800/Reel	Tape Reel
TO-220AB	BYV32-200HE3/45 ⁽¹⁾	1.85	45	50/Tube	Tube
ITO-220AB	BYVF32-200HE3/45 ⁽¹⁾	1.97	45	50/Tube	Tube
TO-263AB	BYVB32-200HE3/45 ⁽¹⁾	1.35	45	50/Tube	Tube
TO-263AB	BYVB32-200HE3/81 ⁽¹⁾	1.35	81	800/Reel	Tape Reel

Note:

(1) Automotive grade AEC Q101 qualified



RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

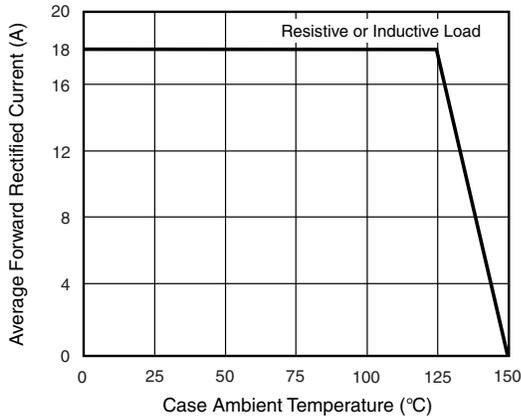


Figure 1. Forward Current Derating Curve

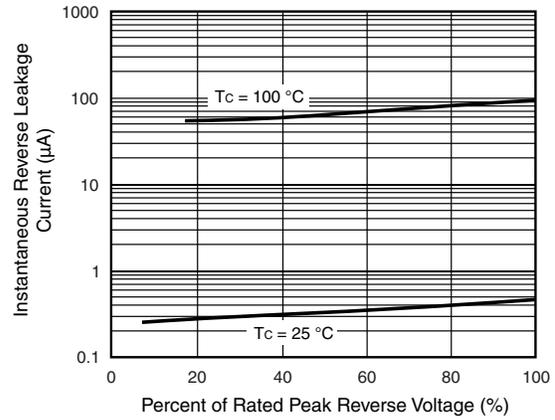


Figure 4. Typical Reverse Leakage Characteristics Per Diode

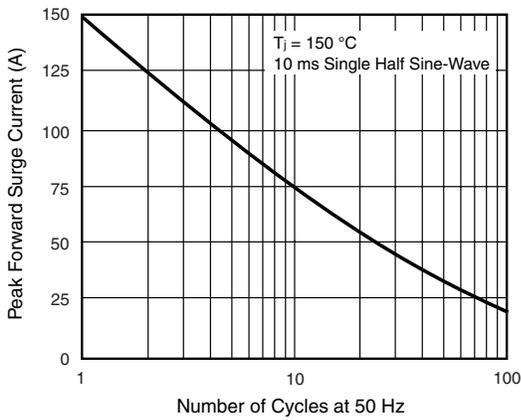


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

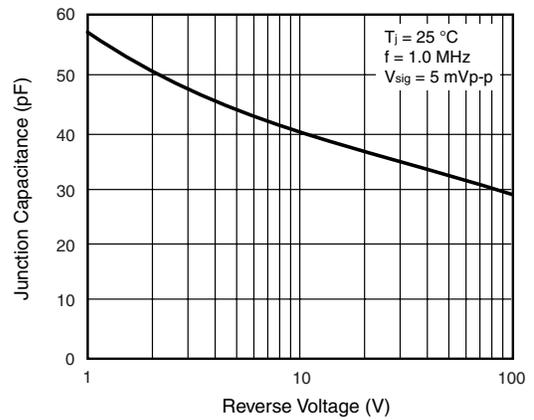


Figure 5. Typical Junction Capacitance Per Diode

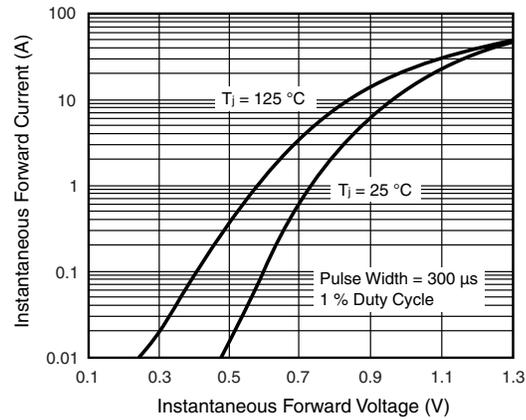
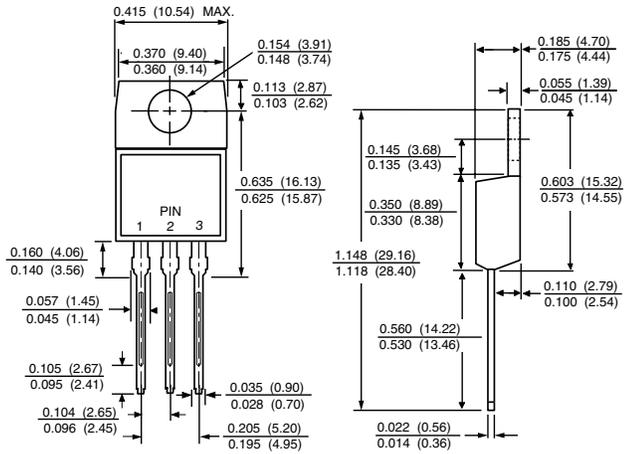


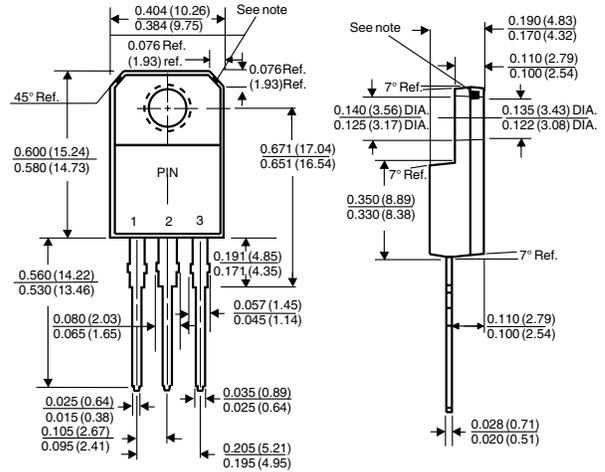
Figure 3. Typical Instantaneous Forward Characteristics Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB

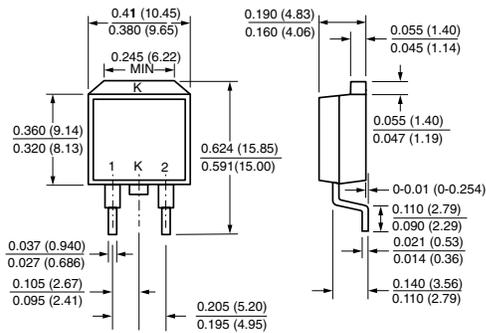


ITO-220AB

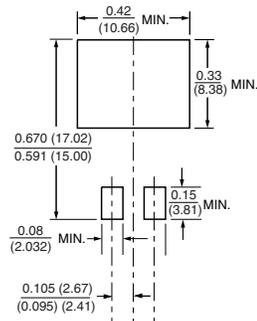


Note: Copper exposure is allowable for 0.005 (0.13) max. from the body

TO-263AB



Mounting Pad Layout





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